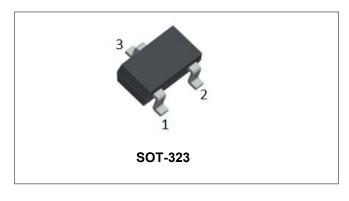






# BAS19W-BAS21W SURFACE MOUNT FAST SWITCHING DIODE



#### **Features**

- High Conductance
- Fast Switching
- Surface Mount Package Ideally Suited for Automatic Insertion
- For General Purpose and Switching
- Plastic Material UL Recognition Flammability Classification 94V-O
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

#### **Schematic & Pin Configuration**



#### **Mechanical Characteristics**

Case: SOT-323, Molded Plastic

Terminals: Plated leads Solderable per MIL-STD-202,

Method 208

• Weight: 0.006g

• Mounting Position: Any

# Maximum Ratings@T<sub>A</sub>=25°C unless otherwise specified

Characteristic	Symbol	BAS19W	BAS20W	BAS21W	Units
Non-Repetitive Peak Reverse Voltage	$V_{RM}$	120	200	250	V
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	100	150	200	V
RMS Reverse Voltage(Note 1)	$V_{R(RMS)}$	70	105	140	٧
Forward Continuous Current (Note 1)	I <sub>FM</sub>	400		mA	
Average Rectified Output Current(Note 1)	lo	200		mA	
Non-Repetitive Peak Forward Surge Current @t=1us	Forward Surge Current @t=1us I <sub>FSM</sub> 2.5		Α		
Power Dissipation	P <sub>D</sub>	200		mW	
Thermal Resistance, Junction to Ambient(Note 1)	RθJA	625		°C/W	
Junction and Storage Temperature Range	$T_J$ , $T_{STG}$	-65 to +150		°C	

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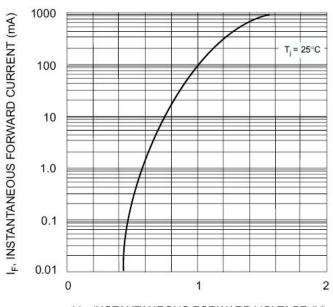
## Electrical Characteristics @T<sub>A</sub>=25°C unless otherwise specified

Characteristic	Symbol	Min	Max	Units	Test Condition
Forward Voltage*	V <sub>F</sub>	-	1.00 1.25	V	@I <sub>F</sub> =100mA @I <sub>F</sub> =200mA
Reverse Leakage Current*	I <sub>R</sub>	-	100	nA	@Rated DC Blocking Voltage
Capacitance between terminals	Ст	-	5	pF	V <sub>R</sub> =0V, f=1.0MHz
Reverse Recovery Time	t <sub>rr</sub>	-	50	ns	$ \begin{array}{l} I_F = I_R = 30 mA, \\ I_{RR} = 0.1 \times I_R, \ R_L = 100 \Omega \end{array} $

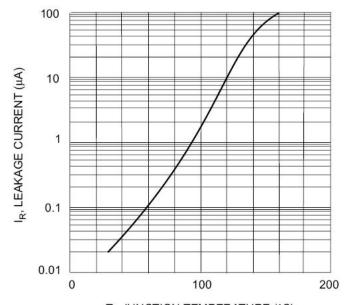
<sup>\*</sup> Pulse width < 300 μs, duty cycle < 2%

Note: 1. Device mounted on fiberglass substrate 40×40×1.5mm

### **Ratings and Characteristics Curves**



V<sub>F</sub>, INSTANTANEOUS FORWARD VOLTAGE (V) Fig. 1 Forward Characteristics



T<sub>j</sub>, JUNCTION TEMPERATURE (°C) Fig. 2 Leakage Current vs Junction Temperature

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## **Ordering Information**

Device	Package	Shipping
BAS19W-BAS21W	SOT-323 (Pb-Free)	3000pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

## **Marking Diagram**

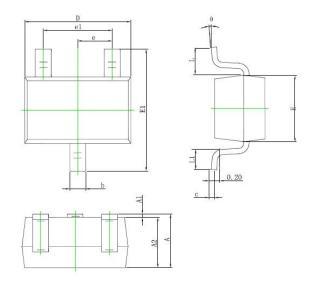
Marking before 16441(Date Code)

Part Number	Device Marking Code
BAS19W	A8
BAS20W	A80
BAS21W	A82

Marking from 16441(Date Code)

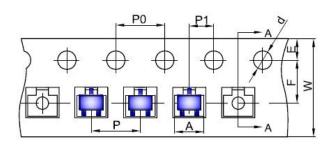
Part Number	Device Marking Code	
BAS19W	KA8	
BAS20W	KT2	
BAS21W	KT3	

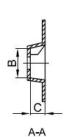
#### **Mechanical Dimensions SOT-323**



OVMDOL	Millimeters		Inches	
SYMBOL	MIN. MAX.		MIN.	MAX.
Α	0.900	1.100	0.035	0.043
A1	0.000	0.100	0.000	0.004
A2	0.900	1.000	0.035	0.039
b	0.200	0.400	0.008	0.016
С	0.080	0.150	0.003	0.006
D	2.000	2.200	0.079	0.087
E	1.150	1.350	0.045	0.053
E1	2.150	2.450	0.085	0.096
е	0.650 TYP.		0.026 TYP.	
e1	1.200	1.400	0.047	0.055
L	0.525 REF.		0.021 REF.	
L1	0.260	0.460	0.010	0.018
θ	0°	8°	0°	8°

# **Carrier Tape Specification SOT-323**





SYMBOL	Millimeters			
STWIBUL	Min.	Max.		
Α	2.20	2.30		
В	2.50	2.60		
С	1.14	1.24		
d	1.45	1.65		
E	1.65	1.85		
F	3.40	3.60		
Р	3.90	4.10		
P0	3.90	4.10		
P1	1.90	2.10		
W	7.90	8.30		

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